Supporting Information

Towards Promoting Plant Growth and Fruit Maturation: Highly Efficient and Thermally Stable Cr³⁺ Doped Far-Red Phosphor

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Fig. S1 XRD patterns of the BaGd₂Al₂Ga_{2-x}GeO₁₂:xCr³⁺ (x = 0.01, 0.07, 0.13).



Fig. S2 Difference Rietveld plot of BaGd₂Al₂Ga_{2-x}GeO₁₂:xCr³⁺ (a) x = 0.01, (b) x = 0.13; (c) Volume *V* with the increase of the Cr³⁺ concentration.

Formula	<i>y</i> = 0	<i>y</i> = 0.01	<i>y</i> = 0.07	<i>y</i> = 0.13
Space Group	Ia-3d			
Cell parameters a/b/c (Å)	12.2468(12)	12.2471(16)	12.2502(14)	12.2539(15)
Cell Volume V (Å ³)	1836.82(6)	1836.97(7)	1838.33(6)	1840.02(7)
2θ -interval, °	5-120			
$R_{ m wp}$,%	6.5	7.06	6.61	6.68
$R_{ m p}$,%	5.08	5.54	5.14	5.19
χ^2	2.4	2.55	2.35	1.93
$R_{ m B}$,%	1.18	1.21	1.26	1.23

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Table S1 Crystallographic data of $BaGd_2Al_2Ga_{2-x}GeO_{12}$: xCr^{3+} with different x values.

	DaU	$u_2 A_{12} U a_{2-x} U C U_{12}$	$\lambda C = (0 \ge \lambda \ge 0.1$	J.		
Atom	x	<u> </u>	Z = Z	B _{iso}	Occ.	
BaGd ₂ Al ₂ Ga ₂ GeO ₁₂						
Ba	0.25	0.125	0	1.54(7)	0.33333	
Gd	0.25	0.125	0	1.54(7)	0.66667	
Gel	0	0	0	2.79(11)	0.5	
Gal	0	0	0	2.79(11)	0.001(10)	
A11	0	0	0	2.79(11)	0.500(10)	
Ga2	0.25	0.375	0	1.00(9)	0.576(8)	
A12	0.25	0.375	0	1.00(9)	0.424(8)	
01	0.0326(4)	0.0491(4)	0.6503(4)	1.21(15)	1	
		BaGd ₂ Al ₂ Ga _{1.9}	99GeO ₁₂ :0.01Cr ³	+		
Ba	0.25	0.125	0	1.26(7)	0.3333333	
Gd	0.25	0.125	0	1.26(7)	0.6666667	
Gel	0	0	0	2.64(12)	0.5	
Gal	0	0	0	2.64(12)	0.001(11)	
Al1	0	0	0	2.64(12)	0.500(11)	
Ga2	0.25	0.375	0	1.00(9)	0.595(9)	
A12	0.25	0.375	0	1.00(9)	0.405(9)	
0	0.0340(5)	0.0475(5)	0.6493(4)	1.26(16)	1	
		BaGd ₂ Al ₂ Ga _{1.9}	₉₃ GeO ₁₂ :0.07Cr ³	+		
Ba	0.25	0.125	0	1.45(7)	0.3333333	
Gd	0.25	0.125	0	1.45(7)	0.6666667	
Gel	0	0	0	2.66(11)	0.5	
Gal	0	0	0	2.66(11)	0.001(10)	
A11	0	0	0	2.66(11)	0.500(10)	
Ga2	0.25	0.375	0	1.00(9)	0.560(8)	
A12	0.25	0.375	0	1.00(9)	0.440(8)	
0	0.0322(4)	0.0480(5)	0.6512(4)	1.14(15)	1	
$BaGd_{2}Al_{2}Ga_{1.87}GeO_{12}{:}0.013Cr^{3+}$						
Ba	0.25	0.125	0	1.51(7)	0.3333333	
Gd	0.25	0.125	0	1.51(7)	0.66666667	
Gel	0	0	0	2.49(11)	0.5	
Gal	0	0	0	2.49(11)	0.001(10)	
A11	0	0	0	2.49(11)	0.500(10)	
Ga2	0.25	0.375	0	1.00(9)	0.561(8)	

Table S2 Fractional atomic coordinates and isotropic displacement parameters (Å²) of BaGd₂Al₂Ga_{2,x}GeO₁₂:xCr³⁺(0 $\le x \le 0.13$).

Atom	x	У	Ζ	$B_{ m iso}$	Occ.
Al2	0.25	0.375	0	1.00(9)	0.439(8)
0	0.0332(5)	0.0491(5)	0.6506(4)	1.44(15)	1

Table S3 Main bond lengths (Å) of BaGd ₂ Al ₂ Ga _{2-x} GeO ₁₂ :xCr ³⁺ .					
$BaGd_2Al_2Ga_{2-x}GeO_{12}:xCr^{3+}$					
		x = 0			
Ba—O ⁱ	2.5117(48)	Ba—O ⁱⁱ	2.3617(48)		
Y—O ⁱ	2.5117(48)	Y—O ⁱⁱ	2.3617(48)		
Ge1—O ⁱⁱⁱ	1.9771(48)	Ga1—O ⁱⁱⁱ	1.9771(48)		
Al1—O ⁱⁱⁱ	1.9771(48)	Ga2—O ^{iv}	1.7700(48)		
Ga2—O ^v	3.3676(48)	Al2—O ^{iv}	1.7700(48)		
	x	r = 0.01			
Ba—O ⁱ	2.5323(49)	Ba—O ⁱⁱ	2.3772(60)		
Y—O ⁱ	2.5323(49)	Y—O ⁱⁱ	2.3772(60)		
Ge1—O ⁱⁱⁱ	1.9634(50)	Ga1—O ⁱⁱⁱ	1.9634(50)		
Al1—O ⁱⁱⁱ	1.9634(50)	Ga2—O ^{iv}	1.7611(60)		
Ga2—O ^v	3.3529(53)	Al2—O ^{iv}	1.7611(60)		
	x	r = 0.07			
Ba—O ⁱ	2.5262(49)	Ba—O ⁱⁱ	2.3492(57)		
Y—O ⁱ	2.5262(49)	Y—O ⁱⁱ	2.3492(57)		
Ge1—O ⁱⁱⁱ	1.9829(50)	Ga1—O ⁱⁱⁱ	1.9829(50)		
Al1—O ⁱⁱⁱ	1.9829(50)	Ga2—O ^{iv}	1.7615(54)		
Ga2—O ^v	3.3821(50)	Al2—O ^{iv}	1.7615(54)		
x = 0.13					
Ba—O ⁱ	2.5148(49)	Ba—O ⁱⁱ	2.3672(60)		
Y—O ⁱ	2.5148(49)	Y—O ⁱⁱ	2.3672(60)		
Ge1—O ⁱⁱⁱ	1.9832(50)	Ga1—O ⁱⁱⁱ	1.9832(50)		
Al1—O ⁱⁱⁱ	1.9832(50)	Ga2—O ^{iv}	1.7638(59)		
Ga2—O ^v	3.3657(53)	Al2—O ^{iv}	1.7638(59)		

Symmetry codes: Symmetry codes: (i) -x+1/4, -z-3/4, y+1/4; (ii) -z+1, -x, -y; (iii) -x, y, z+1/2; (iv) z+1/2, -x+1/2, -y; (v) z+1/4, y+1/4, -x+1/4

Current	Voltage	Input electrical	FR output power	photoelectric
(mA)	(V)	power (mW)	(mW)	efficiency
50	2.76	138	19.46	14.10%
100	2.87	287	36.78	12.82%
150	2.96	444	51.61	11.62%
200	3.04	608	66.25	10.90%
250	3.10	775	77.33	9.98%
300	3.15	945	89.96	9.52%
350	3.19	1117	98.67	8.84%
400	3.26	1304	107.36	8.23%
350 400	3.19 3.26	1117 1304	98.67 107.36	8.84% 8.23%

 Table S4
 Detailed measured data of the FR pc-LED output power and efficiency under different current drive.